

Silicon NPN Power Transistors

2SD1666

DESCRIPTION

- With TO-220F package
- Complement to type 2SB1133
- High reliability
- Wide area of safe operation

APPLICATIONS

- For low-frequency and general-purpose amplifier applications

PINNING

PIN	DESCRIPTION
1	Base
2	Collector
3	Emitter

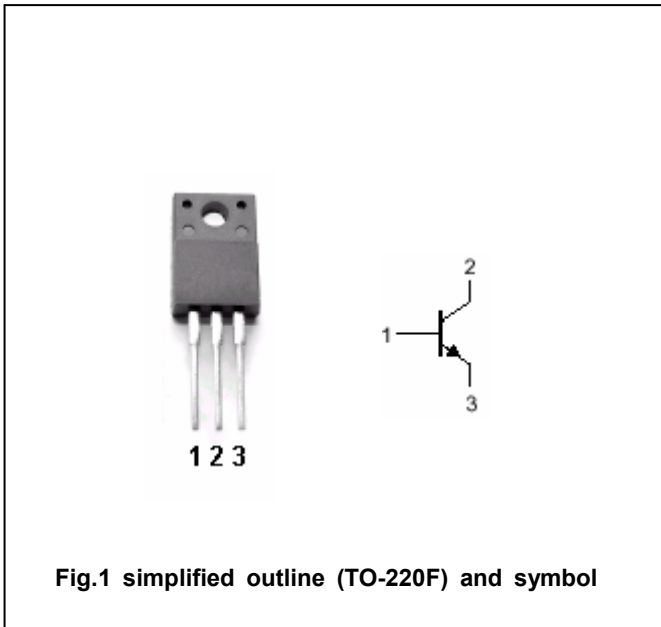


Fig.1 simplified outline (TO-220F) and symbol

Absolute maximum ratings (Ta=25°C)

SYMBOL	PARAMETER	CONDITIONS	MAX	UNIT
V _{CBO}	Collector-base voltage	Open emitter	60	V
V _{CEO}	Collector-emitter voltage	Open base	60	V
V _{EBO}	Emitter-base voltage	Open collector	6	V
I _C	Collector current		3	A
I _{CM}	Collector current-peak		8	A
P _C	Collector dissipation	T _a =25°C	2	W
		T _C =25°C	25	
T _j	Junction temperature		150	°C
T _{stg}	Storage temperature		-40~150	°C

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CHARACTERISTICS

T_j=25°C unless otherwise specified

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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C =5mA ; R _{BE} =∞	60			V
V _{(BR)CBO}	Collector-base breakdown voltage	I _C =1mA ; I _E =0	60			V
V _{(BR)EBO}	Emitter-base breakdown voltage	I _E =1mA ; I _C =0	6			V
V _{CEsat}	Collector-emitter saturation voltage	I _C =2A ; I _B =0.2A		0.6	1.0	V
V _{BE}	Base-emitter on voltage	I _C =0.5A ; V _{CE} =5V		0.7	1.0	V
I _{CBO}	Collector cut-off current	V _{CB} =40V ; I _E =0			100	μA
I _{EBO}	Emitter cut-off current	V _{EB} =4V ; I _C =0			100	μA
h _{FE-1}	DC current gain	I _C =0.5A ; V _{CE} =5V	70		280	
h _{FE-2}	DC current gain	I _C =3A ; V _{CE} =5V	20			
C _{OB}	Output capacitance	I _E =0 ; V _{CB} =10V ; f=1MHz		60		pF
f _T	Transition frequency	I _C =0.5A ; V _{CE} =5V		8		MHz

◆ h_{FE-1} Classifications

Q	R	S
70-140	100-200	140-280

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PACKAGE OUTLINE

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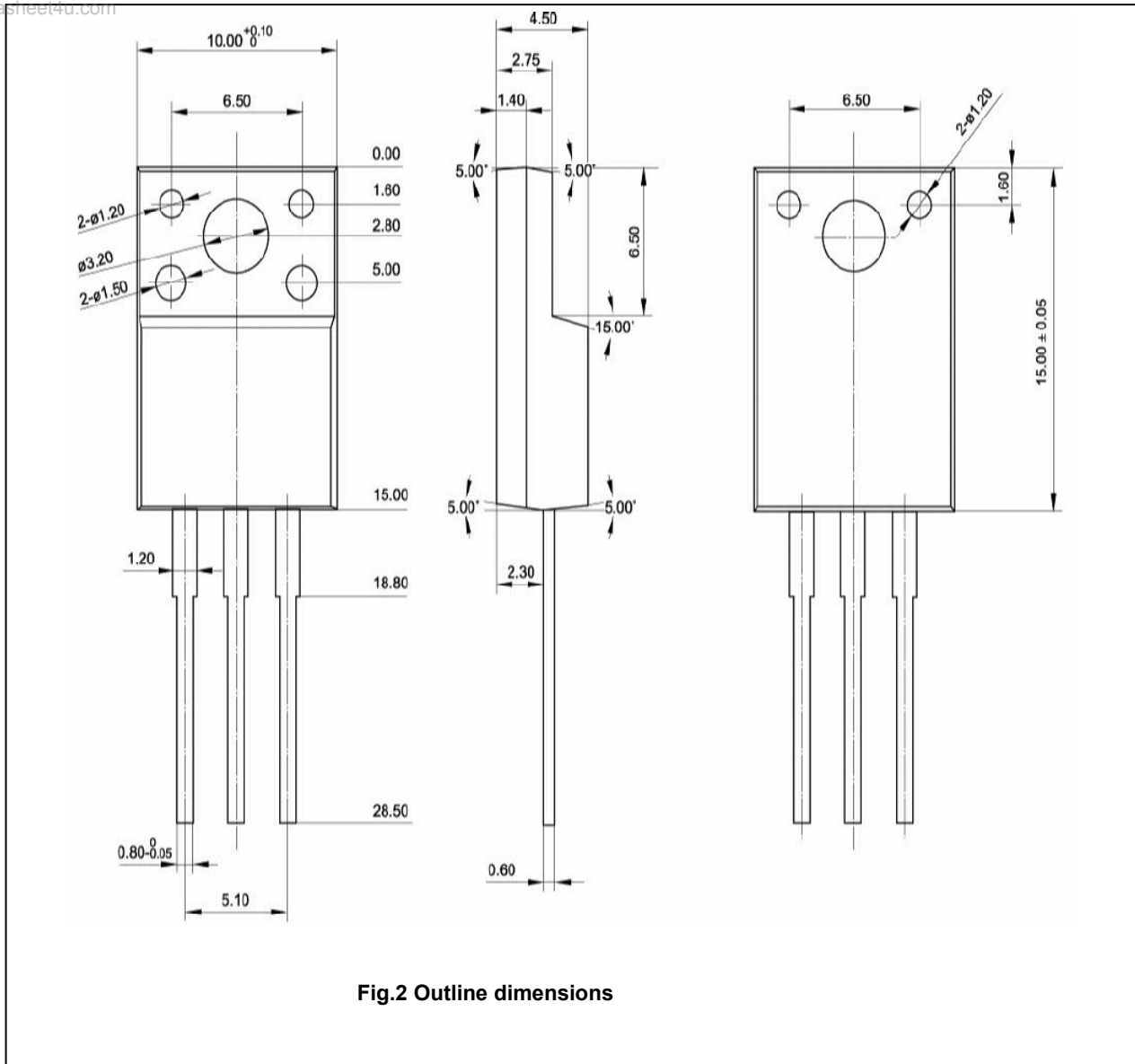


Fig.2 Outline dimensions

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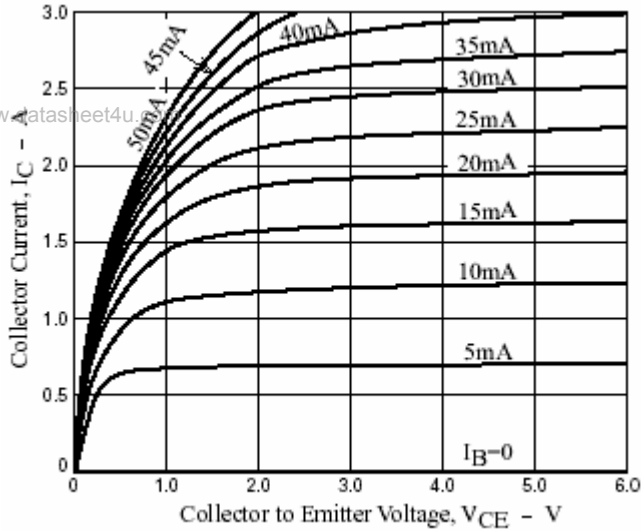


Fig.3 Static Characteristic

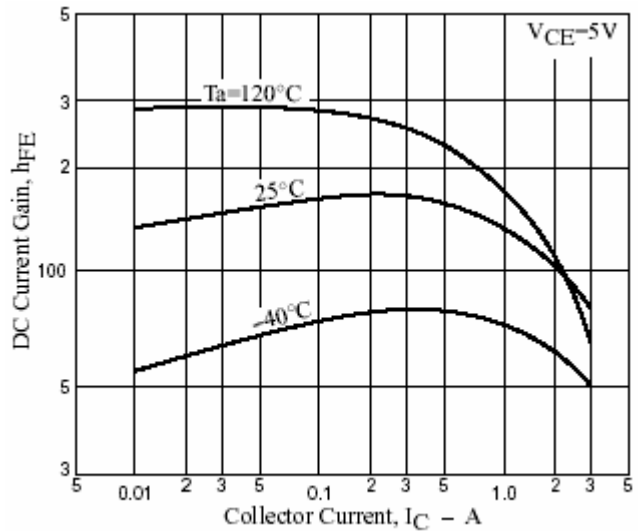


Fig.4 DC current Gain

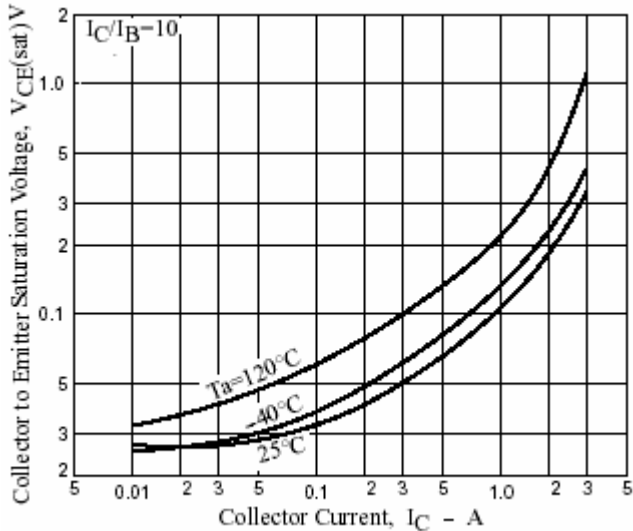


Fig.5 Collector-Emitter Saturation Voltage

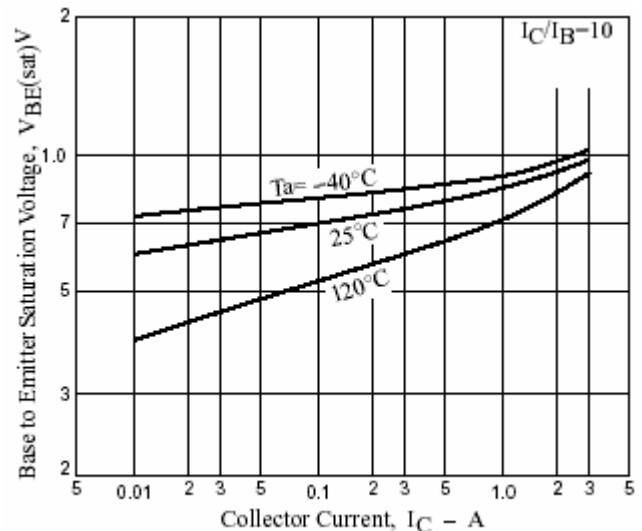


Fig.6 Base-Emitter Saturation Voltage

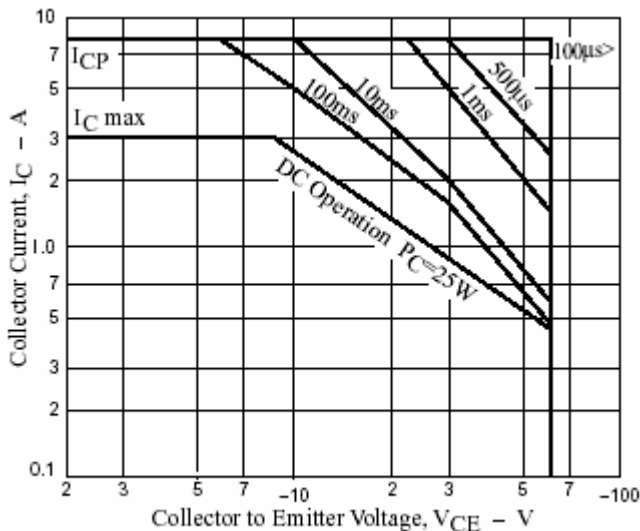


Fig.7 Safe Operating Area